Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3098137	memory or storage	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/28 16:49
L2	549220	1 and (dynamic or $2ram or fpga or field adj programmable)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/28 16:51
L3	750	2 and cell with capacitor with transistor with gate with (bit or bitline) with (drain or source) with (row or word or wordline)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/28 16:53
L5	114	3 and cell with (source or drain) with node with stor$5	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/28 16:54